



DUAL P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	RDS(ON) max	Ι _D T _A = +25°C
2017	90mΩ @ V _{GS} = -4.5V	-3.1A
-20V	$120m\Omega @ V_{GS} = -2.5V$	-2.6A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, which makes it ideal for high-efficiency power management applications.

- Load Switch
- **Power Management Functions**
- Portable Power Adaptors

Features

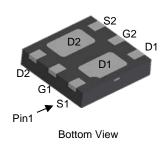
- PCB Footprint of 4mm²
- Low On-Resistance
- Low Input Capacitance
- Low Profile, 0.6mm Maximum Height
- **ESD** Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

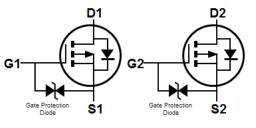
Mechanical Data

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Lead-Frame. Solderable per MIL-STD-202, Method 208 (e4)
- Terminals Connections: See Diagram Below
- Weight: 0.0065 grams (Approximate)

U-DFN2020-6 (Type B)







Internal Schematic

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2045UFDB-7	U-DFN2020-6 (Type B)	3000/Tape & Reel
DMP2045UFDB-13	U-DFN2020-6 (Type B)	10,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

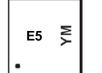
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds. 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Site 1:



E5 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key												
Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	Н		J	К	L	М	N	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

Site 2:

E5 YWX E5 = Product Type Marking Code YWX = Date Code Marking

Y = Year (ex: 0 = 2020)

W = Week (ex: a = week 27; z represents week 52 and 53) X = Internal Code (ex: U = Monday)

Date	Code	Kev
Daio	oouc	1109

Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	0	1	2	3	4	5	6	7	8	9	0	1
Week		1-	26	2			27-52 53					
Code		A	-Z		a-z			Z				
Internal Code	Sur	۱ I	Mon		Tue	W	ed	Thu		Fri		Sat
Code	Т		U		V	V	V	Х		Y		Z



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	-20	V		
Gate-Source Voltage	V _{GSS}	±8	V		
Continuous Drain Current (Note 6) V_{GS} = -4.5V	Steady State	T _A = +25°C T _A = +70°C	ID	-3.1 -2.4	A
Maximum Continuous Body Diode Forward Current ((Note 6)		Is	-1.8	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%))		I _{DM}	-24	A
Avalanche Current (Note 7) L = 0.1mH	I _{AS}	-11	A		
Avalanche Energy (Note 7) L = 0.1mH			E _{AS}	7	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	PD	0.74	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{ƏJA}	170	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	1.29	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{OJA}	97	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

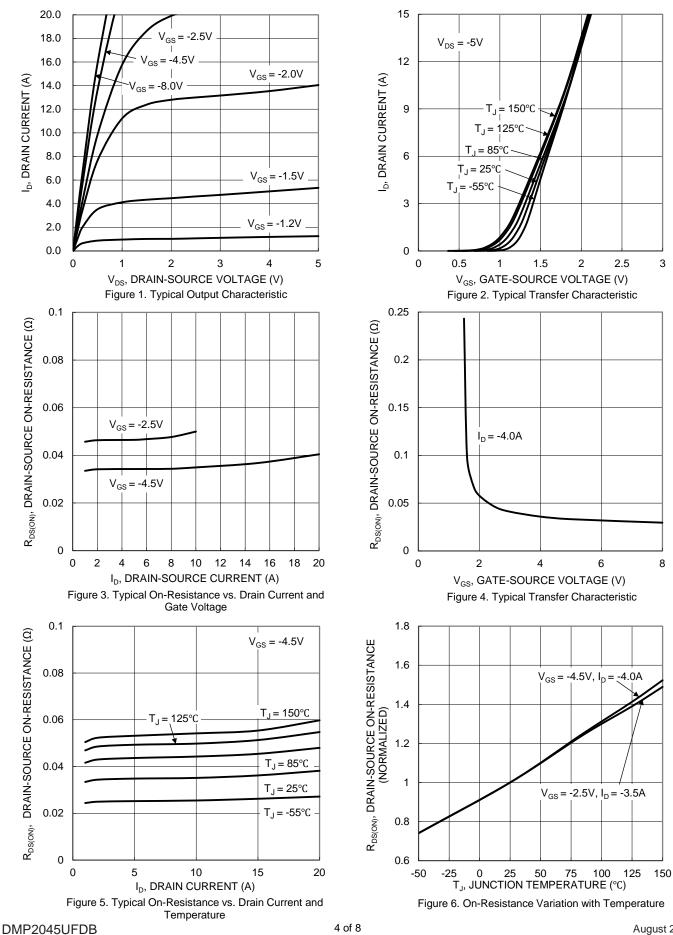
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 7)			- 71					
Drain-Source Breakdown Voltage	BV _{DSS}	-20	—	_	V	$V_{GS} = 0V, I_D = -250 \mu A$		
Zero Gate Voltage Drain Current TJ = +25°C	I _{DSS}	—	-	-1.0	μA	$V_{DS} = -20V, V_{GS} = 0V$		
Gate-Source Leakage	Igss		_	±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$		
ON CHARACTERISTICS (Note 7)								
Gate Threshold Voltage	V _{GS(TH)}	-0.3	—	-1.0	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$		
Ctatia Dasia Course On Desistence		—	35	90		$V_{GS} = -4.5V, I_D = -4A$		
Static Drain-Source On-Resistance	R _{DS(ON)}	—	47	120	mΩ	V _{GS} = -2.5V, I _D = -3.5A		
Diode Forward Voltage	V _{SD}	—	-0.75	-1.2	V	$V_{GS} = 0V, I_{S} = -1.0A$		
DYNAMIC CHARACTERISTICS (Note 8)	<u>.</u>							
Input Capacitance	C _{iss}	—	634	_	pF			
Output Capacitance	Coss	—	81	_	pF	$V_{DS} = -10V, V_{GS} = 0V,$ - f = 1.0MHz		
Reverse Transfer Capacitance	Crss	—	66	—	pF			
Gate Resistance	Rg	—	20	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$		
Total Gate Charge (V _{GS} = -4.5V)	Qg	—	6.8	—	nC			
Gate-Source Charge	Q _{gs}		0.7	—	nC	$V_{DS} = -4.5V, I_D = -4A,$ $V_{DS} = -10V$		
Gate-Drain Charge	Q _{gd}	—	1.6	—	nC	VDS = -10V		
Turn-On Delay Time	t _{D(ON)}		4.2	—	ns			
Turn-On Rise Time	t _R	—	3.4	—	ns	V _{DS} = -10V, V _{GS} = -4.5V,		
Turn-Off Delay Time	t _{D(OFF)}	—	23	—	ns	$R_L = 3.3\Omega, R_g = 1\Omega$		
Turn-Off Fall Time	t _F		9.6	_	ns			
Body Diode Reverse Recovery Time	t _{RR}	—	1.8	—	ns	I _S = -1.0A, dl/dt = 100A/µs		
Body Diode Reverse Recovery Charge	Q _{RR}	_	9.4	_	nC	I _S = -1.0A, dl/dt = 100A/µs		

 Device mounted on FR-4 substrate PCB, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PCB, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect. Notes:

8. Guaranteed by design. Not subject to product testing.

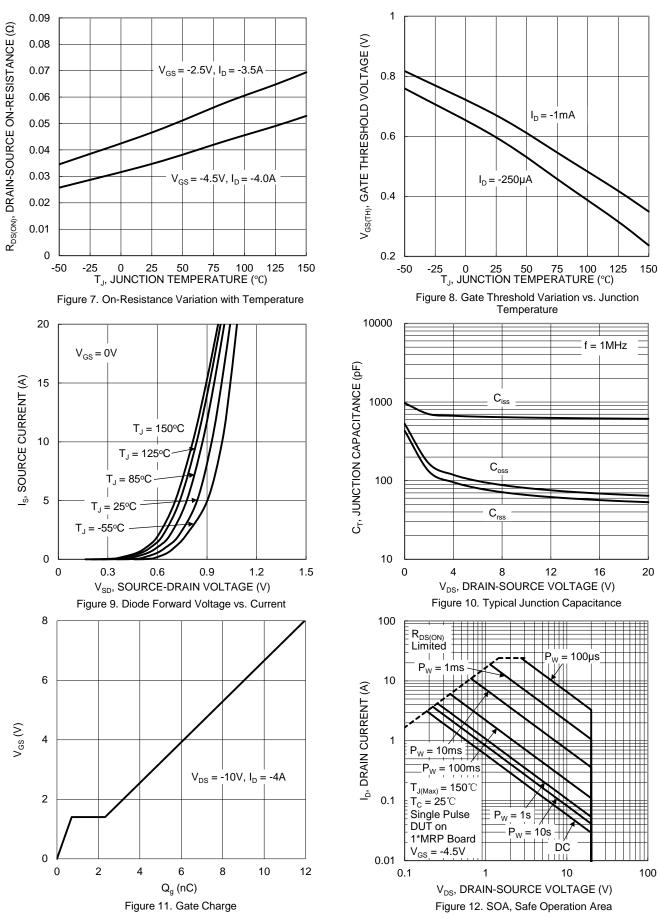


DMP2045UFDB



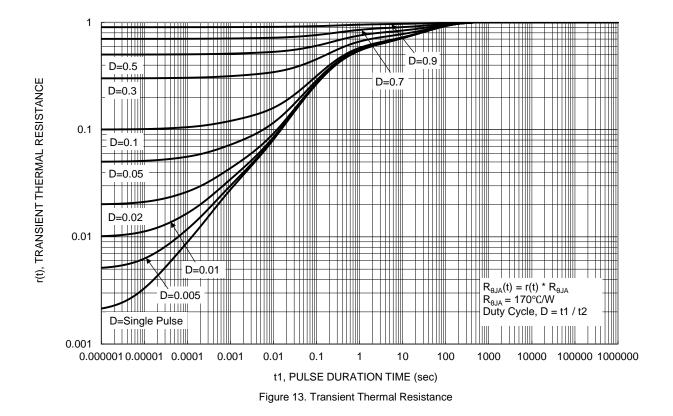
Document number: DS42596 Rev. 2 - 2





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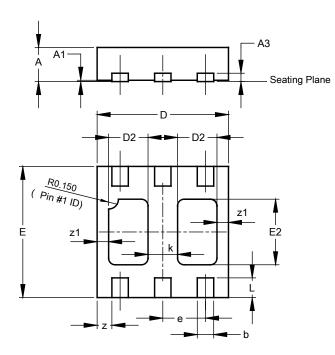






Package Outline Dimensions

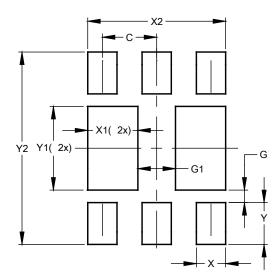
Please see http://www.diodes.com/package-outlines.html for the latest version.



	U-DFN2020-6 Type B							
Dim	Min	Max	Тур					
Α	0.545	0.605	0.575					
A1	0.00	0.05	0.02					
A3	-	-	0.13					
b	0.20	0.30	0.25					
D	1.95	2.075	2.00					
D2	0.50	0.70	0.60					
е	-	-	0.65					
Е	1.95	2.075	2.00					
E2	0.90	1.10	1.00					
k	-	-	0.45					
L	0.25	0.35	0.30					
z	-	-	0.225					
z1	-	-	0.175					
All	Dimens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	0.150
G1	0.450
Х	0.350
X1	0.600
X2	1.650
Y	0.500
Y1	1.000
Y2	2.300



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